

IEC SYSTEM FOR MUTUAL RECOGNITION OF TEST  
CERTIFICATES FOR ELECTRICAL EQUIPMENT  
(IECEE) CB SCHEME

SYSTEME CEI D'ACCEPTATION MUTUELLE DE  
CERTIFICATS D'ESSAIS DES EQUIPEMENTS  
ELECTRIQUES (IECEE) METHODE OC

## CB TEST CERTIFICATE

Product  
Produit  
Name and address of the applicant  
Nom et adresse du demandeur

Name and address of the manufacturer  
Nom et adresse du fabricant

Name and address of the factory  
Nom et adresse de l'usine

Note: When more than one factory, please report on page 2  
Note: Lorsque il y plus d'une usine, veuillez utiliser la 2<sup>ème</sup> page

Ratings and principal characteristics  
Valeurs nominales et caractéristiques principales

Trademark (if any)  
Marque de fabrique (si elle existe)

Type of Manufacturer's Testing Laboratories used  
Type de programme du laboratoire d'essais  
constructeur  
Model / Type Ref.  
Ref. De type

Additional information (if necessary may also be  
reported on page 2)  
Les informations complémentaires (si nécessaire,,  
peuvent être indiqués sur la 2<sup>ème</sup> page  
A sample of the product was tested and found  
to be in conformity with  
Un échantillon de ce produit a été essayé et a été  
considéré conforme à la  
As shown in the Test Report Ref. No. which forms part  
of this Certificate  
Comme indiqué dans le Rapport d'essais numéro de  
référence qui constitue partie de ce Certificat

This CB Test Certificate is issued by the National Certification Body  
Ce Certificat d'essai OC est établi par l'Organisme **National de Certification**

## CERTIFICAT D'ESSAI OC

Component IC Current Limiter

TEXAS INSTRUMENTS INC  
MS 8712  
12500 TI BLVD  
DALLAS TX 75243  
UNITED STATES

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MS 8712  
12500 TI BLVD  
DALLAS TX 75243  
UNITED STATES

TEXAS INSTRUMENTS DE MEXICO S DE R L DE C V  
JESUS RIVERA FRANCO # 507 CD INDUSTRIAL 20290  
AGUASCALIENTES AGS  
MEXICO

☒ Additional Information on page 2

Input Voltage:  
2.7 Vdc to 5.5 Vdc  
Output Continuous Rating:  
0.25 A to 0.5 A  
Output Current Limit:  
5.0 A  
Ambient:  
-40 to 25°C



TPS2041, TPS2042, TPS2043, TPS2044, TPS2045, TPS2046,  
See Page 2

☒ Additional Information on page 2

IEC 60950-1(ed.2), IEC 60950-1(ed.2);am1,  
IEC 60950-1(ed.2);am2

E169910-A32-CB-1 issued on 2015-07-27



- ☒ UL (US), 333 Pfingsten Rd IL 60062, Northbrook, USA
- ☐ UL (Demko), Borupvang 5A DK-2750 Ballerup, DENMARK
- ☐ UL (JP), Marunouchi Trust Tower Main Building 6F, 1-8-3 Marunouchi, Chiyoda-ku, Tokyo 100-0005, JAPAN
- ☐ UL (CA), 7 Underwriters Road, Toronto, M1R 3B4 Ontario, CANADA

For full legal entity names see [www.ul.com/ncbnames](http://www.ul.com/ncbnames)

Date: 2015-08-06

Signature:

Jolanta M. Wroblewska



Ref. Certif. No.

**US-25744-UL****Model Details:**

TPS2041,TPS2042,TPS2043,TPS2044,TPS2045,TPS2046,TPS2047,TPS2048,TPS2051,TPS2052,TPS2053,TPS2054,TPS2055,TPS2056,TPS2057,TPS2058 Followed by suffix "A" or "B".

Additional suffixes after the model number designate the type of integrated circuit package, integrated circuit lead types, or other features that are considered not to affect the functionality of the device.

**Factories:**

TEXAS INSTRUMENTS SEMICONDUCTOR MANUFACTURING (CHENGDU) CO., LTD.

NO. 8-8 & NO.8-10, KEXIN RD WEST ZONE OF CHENGDU HI-TECH INDUSTRIAL DEVELOPMENT CHENGDU SICHUAN CHINA

TEXAS INSTRUMENTS TAIWAN LTD

142 HSIN NAN RD, SEC 1 CHUNG HO TAIPEI HSIEN 235 TAIWAN

ASE ASSEMBLY & TEST (SHANGHAI) LTD

#669 GUOSHOUJING RD ZHANGJIANG HI-TECH PARK PUDONG NEW AREA SHANGHAI 201203 CHINA

UTAC THAI LTD

WELGROW INDUSTRIAL ESTATE, 73 MOO5 BANGNA-TRAD (KM 38) RD A BANGPAKONG, T BANGSAMAK CHACHOENGSAO 24180 THAILAND

NANTONG FUJITSU MICROELECTRONICS CO LTD

NO 288 CHONGCHUAN RD CHONGCHUAN DEVELOPMENT ZONE NANTONG JIANGSU 226006 CHINA

TEXAS INSTRUMENTS MALAYSIA SDN BHD

1 LORONG ENGGANG 33 AMPANG/ULU KLANG 54200 KUALA LUMPUR MALAYSIA

HANA MICROELECTRONICS CO LTD (JIA XING)

18 HANA RD XINCHENG INDUSTRIAL PARK XIUZHOU DISTRICT JIAXING ZHEJIANG 314000 CHINA

TI (PHILIPPINES) INC

CLARK TI SPECIAL ECONOMIC ZONE CLARK FREEPORT ZONE ANGELES PAMPANGA PHILIPPINES

HANA SEMICONDUCTOR (AYUTTHAYA) CO LTD

HI-TECH IND ESTATE AUTH OF THAILAND 100 MOO1, T BAAN-LEN, A BANG PA-IN KM 59 ASIA RD AYUTTHAYA 13160 THAILAND

CARSEM SEMICONDUCTOR CO LTD

NO 88 WEST SHEN HU ROAD IN DISTRICT 2 SUZHOU INDUSTRIAL PARK JIANGSU 215021 CHINA

**Additional Information:**

Additionally evaluated to EN 60950-1:2006 / A11:2009 / A1:2010 / A12:2011 / A2:2013;

National Differences specified in the CB Test Report.

**Additional information (if necessary)****Information complémentaire (si nécessaire)**

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